**Vishay Semiconductors** 

High Performance Schottky Rectifier, 2.1 A

Anode

-0



www.vishay.com

SMA

PRODUCT SUMMARY					
Package	SMA				
I <sub>F(AV)</sub>	2.1 A				
V <sub>R</sub>	40 V				
V <sub>F</sub> at I <sub>F</sub>	0.54 V				
I <sub>RM</sub>	26 mA at 125 °C				
T <sub>J</sub> max.	150 °C				
Diode variation	Single die				
E <sub>AS</sub>	3.0 mJ				

### FEATURES

- Small foot print, surface mountable
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### DESCRIPTION

The VS-10MQ040NPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UNITS				
I <sub>F(AV)</sub>	DC	2.1	А			
V <sub>RRM</sub>		40	V			
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	120	А			
V <sub>F</sub>	1.5 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.56	V			
TJ	Range	-55 to +150	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-10MQ040NPbF	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	40	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	v			

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDIT	TEST CONDITIONS			
Maximum average forward current See fig. 4	I <sub>F(AV)</sub>	50 % duty cycle at $T_L$ = 123 °C, rectangular waveform On PC board 9 mm <sup>2</sup> island (0.013 mm thick copper pad area)		1.5	А	
Maximum peak one cycle	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	120	А	
non-repetitive surge current I <sub>FSM</sub> See fig. 6		10 ms sine or 6 ms rect. pulse				
Non-repetitive avalanche energy	E <sub>AS</sub>	$T_{J} = 25 \text{ °C}, I_{AS} = 1 \text{ A}, L = 6 \text{ mH}$		3.0	mJ	
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical 1.0		А		

Revision: 01-Aug-14 1 Document Number: 94117 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



COMPLIANT



## **Vishay Semiconductors**

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS		
Maximum forward voltage drop See fig. 1		1 A	T.I = 25 °C	0.54	V	
	V <sub>FM</sub> <sup>(1)</sup>	1.5 A	1j=25 C	0.62		
	VFM ("	1 A	T <sub>J</sub> = 125 °C	0.49		
		1.5 A	1j=125 C	0.56		
Maximum reverse leakage current See fig. 2	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	0.5	mA	
		T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	26		
Threshold voltage	V <sub>F(TO)</sub>		0.36	V		
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> = T <sub>J</sub> maximum 104		104	mΩ	
Typical junction capacitance	CT	$V_R = 10 V_{DC}$ , $T_J = 25 \text{ °C}$ , test signal = 1 MHz 38		pF		
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body 2.0 nH		nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/µs		V/µs		

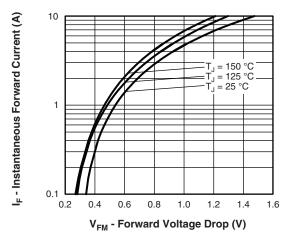
#### Note

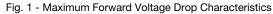
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-55 to +150	°C	
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	DC operation	80	°C/W	
Approvimeto weight			0.07	g	
Approximate weight			0.002	oz.	
Marking device		Case style SMA (similar D-64)	V	IF	

#### Note

<sup>(1)</sup>  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink





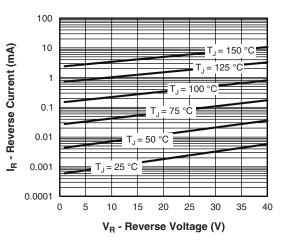


Fig. 2 - Typical Peak Reverse Current vs. Reverse Voltage

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



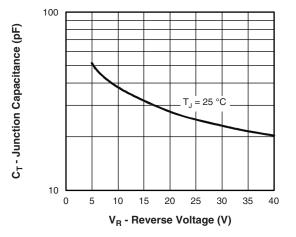


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

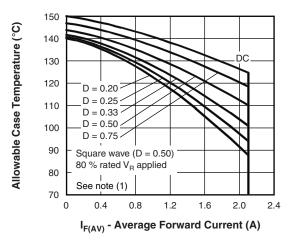


Fig. 4 - Maximum Average Forward Current vs. Allowable Lead Temperature

#### Note



## **Vishay Semiconductors**

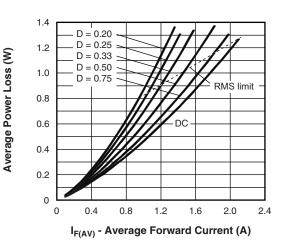


Fig. 5 - Maximum Average Forward Dissipation vs. Average Forward Current

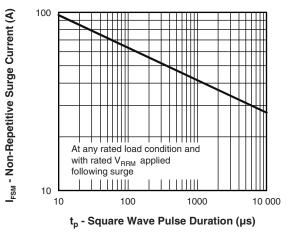


Fig. 6 - Maximum Peak Surge Forward Current vs. Pulse Duration

Revision: 01-Aug-14 3 Document Number: 94117 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

## Vishay Semiconductors



### **ORDERING INFORMATION TABLE**

Device code	VS-	10	м	Q	040	N	TR	PbF
	1	2	3	4	5	6	7	8
	1 -	Visl	nay Sem	niconduc	ctors pro	oduct		
	2 -	Cur	rent rati	ng				
	3 -	M =	SMA					
	4 -	Q =	Schottk	ty "Q" se	eries			
	5 -	Volt	tage rati	ng (040	= 40 V)			
	6 -	N =	new SN	/IA				
	7 -	• N	one = bo	ox (1000	) pieces	)		
		• TI	R = tape	and ree	el (7500	pieces	)	
	8 -	PbF	= lead	(Pb)-fre	е			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95018</u>					
Part marking information		www.vishay.com/doc?95029			
Packaging information	Tape and reel	www.vishay.com/doc?95034			
Fackaging information	Bulk	www.vishay.com/doc?95397			
SPICE model		www.vishay.com/doc?95277			

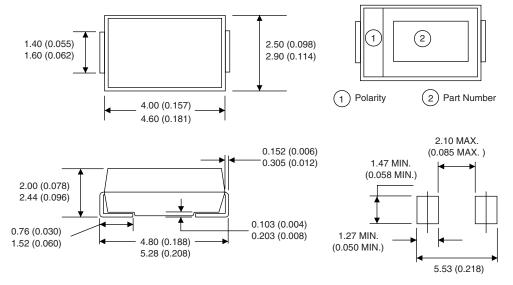


# **Outline Dimensions**

## Vishay High Power Products

**SMA** 

### **DIMENSIONS** in millimeters (inches)



Soldering pad



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.